GD VJLPE1.14

OSLON® Pure 1010

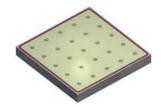
Industry most compact high power chip-scale package LED with high performance, superior robustness and long lifetime.



Applications

- Architecture / Garden Lighting (LED & Laser)
- Downlights/Spotlights
- Features:
- Package: chip level conversion
- Typ. Radiation: 120° (Lambertian emitter)
- Radiant Flux: typ. 1140 mW
- Radiant Efficiency: typ. 55 %

- Medical Illumination
- Photo Therapy



Ordering Information Total radiant flux 1) Ordering Code Type Total radiant flux 1) Ordering Code I_F = 700 mA Φ_E Ordering Code GD VJLPE1.14-T1T4-AD-1 1020.0 ... 1185.0 mW Q65113A0463



Maximum Ratings

Parameter	Symbol		Values
Operating Temperature	T _{op}	min.	-40 °C
	θþ	max.	85 °C
Storage Temperature	T _{stg}	min.	-40 °C
	Stg	max.	85 °C
Junction Temperature	T _j	max.	125 °C
Forward current	I _F	min.	30 mA
	·	max.	1000 mA
Reverse voltage 2)	V _R		Not designed for reverse operation
ESD withstand voltage acc. ANSI/ESDA/JEDEC JS-001 (HBM, Class 0)	V_{ESD}		ESD sensitive device



Characteristics

I_F = 700 mA; T_J = 25 °C

Parameter	Symbol		Values
Dominant Wavelength ³⁾ I _F = 700 mA	λ_{dom}	min. typ. max.	445 nm 453 nm 455 nm
Viewing angle at 50% ${\rm I_v}$	2φ	typ.	120 °
Forward Voltage ⁴⁾ I _F = 700 mA	V _F	min. typ. max.	2.70 V 2.95 V 3.20 V
Reverse current 2)	I _R		Not designed for reverse operation
Electrical thermal resistance junction/solderpoint with efficiency $\eta_{\rm e}$ = 51 %	$R_{thJS\;elec.}$	typ.	6.3 K / W



Brightness Groups

Group	Total radiant flux ¹⁾ I _F = 700 mA min. Φ _E	Total radiant flux ¹⁾ I _F = 700 mA max. Φ _E
T1	1020.0 mW	1060.0 mW
T2	1060.0 mW	1100.0 mW
Т3	1100.0 mW	1140.0 mW
Τ4	1140.0 mW	1185.0 mW

Forward Voltage Groups

Group	Forward Voltage ⁴⁾ I _F = 700 mA min. V _F	Forward Voltage ⁴⁾ I _F = 700 mA max. V _F	
1V	2.70 V	2.75 V	
1W	2.75 V	2.80 V	
1Y	2.80 V	2.85 V	
1Z	2.85 V	2.90 V	
2A	2.90 V	2.95 V	
2B	2.95 V	3.00 V	
2C	3.00 V	3.05 V	
2D	3.05 V	3.10 V	
2E	3.10 V	3.15 V	
2F	3.15 V	3.20 V	

Wavelength Groups

Group	Dominant Wavelength ³⁾ $I_F = 700 \text{ mA}$ min. λ_{dom}	Dominant Wavelength ³⁾ I _F = 700 mA max. λ _{dom}
A	445 nm	448 nm
В	448 nm	450 nm
С	450 nm	453 nm
D	453 nm	455 nm

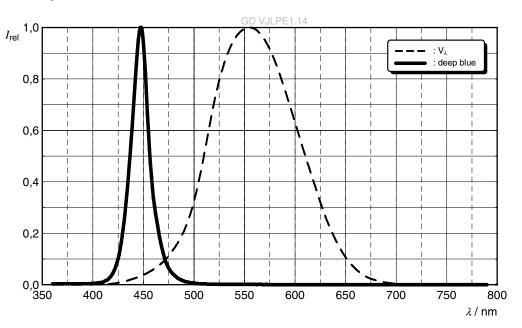


Group Name on LabelExample: T1-A-1VBrightnessWavelengthT1A1V



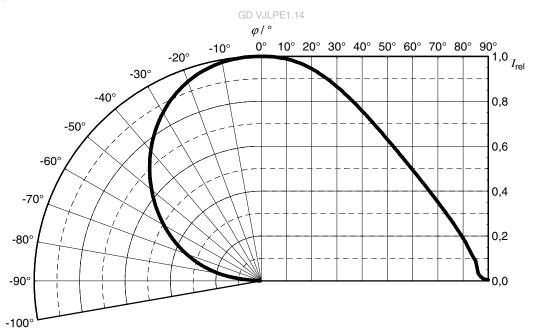
Relative Spectral Emission 5)

 $I_{rel} = f(\lambda); I_{F} = 700 \text{ mA}; T_{J} = 25 \text{ }^{\circ}\text{C}$



Radiation Characteristics ⁵⁾

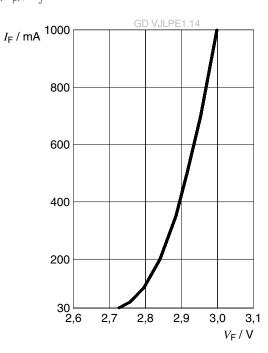
 $I_{rel} = f(\phi); T_J = 25 \ ^{\circ}C$





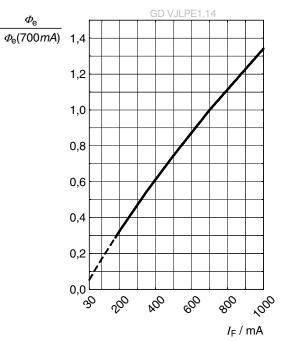
Forward current ⁵⁾

 $I_F = f(V_F); T_J = 25 \ ^{\circ}C$



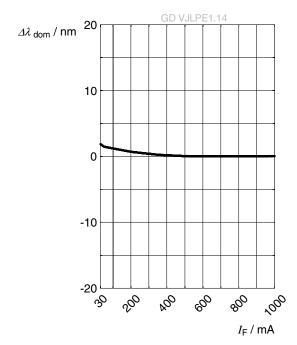
Relative Radiant Power 5), 6)

 $\Phi_{\rm E}/\Phi_{\rm E}(700 \text{ mA}) = f(I_{\rm F}); T_{\rm J} = 25 \text{ °C}$

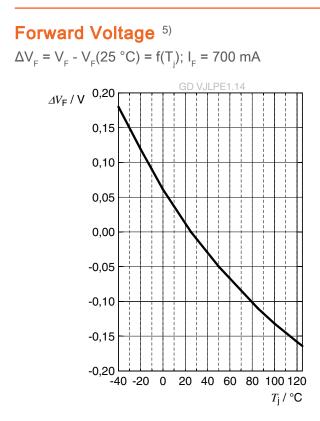


Dominant Wavelength 5)

 $\Delta \lambda_{dom} = f(I_F); T_J = 25 \ ^{\circ}C$

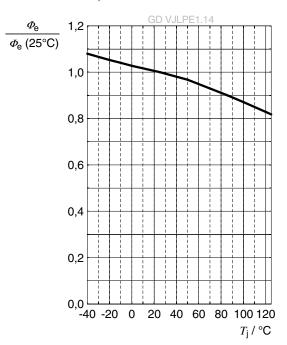






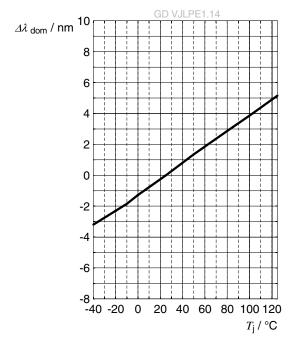
Relative Radiant Power⁵⁾

 $\Phi_{_{\rm E}}/\Phi_{_{\rm E}}(25 \ ^{\circ}{\rm C}) = f(T_{_{\rm I}}); I_{_{\rm F}} = 700 \text{ mA}$

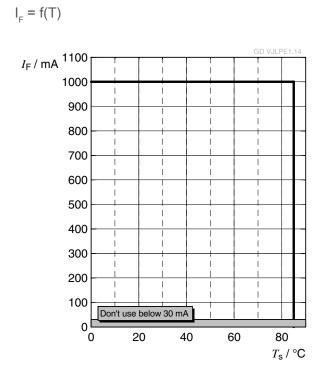


Dominant Wavelength 5)

 $\Delta \lambda_{dom} = \lambda_{dom} - \lambda_{dom} (25 \ ^{\circ}C) = f(T_j); I_F = 700 \ mA$



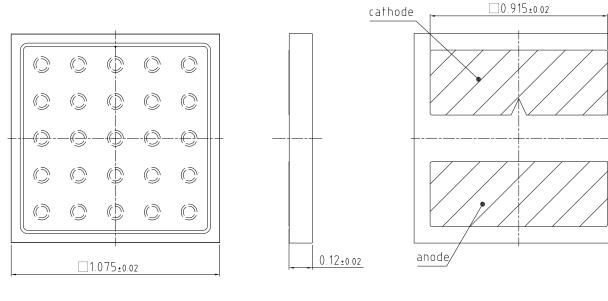




Max. Permissible Forward Current

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Dimensional Drawing 7)



general tolerance ±0.05 lead finish Au C67062-A0269-A1-01

0.24±0.02

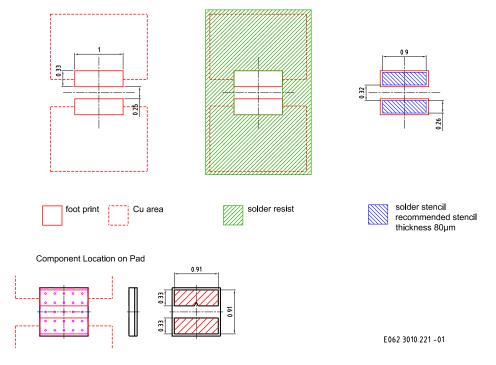
Further Information:

Approximate Weight: 0.8 mg

Package marking: Cathode

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OSRAM
Opto Semiconductors
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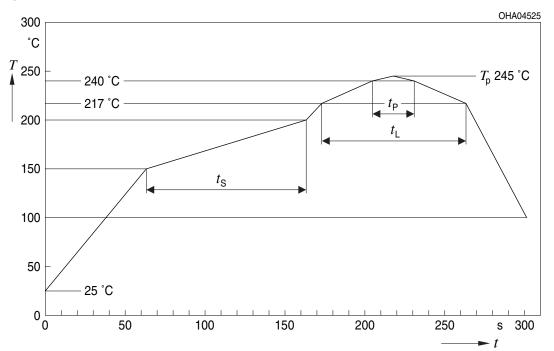
Recommended Solder Pad 7)





Reflow Soldering Profile

Product complies to MSL Level 2 acc. to JEDEC J-STD-020E



Profile Feature	Symbol	Pb-Free (SnAgCu) Assembly			Unit
		Minimum	Recommendation	Maximum	
Ramp-up rate to preheat ^{*)} 25 °C to 150 °C			2	3	K/s
Time t _s T _{smin} to T _{smax}	t _s	60	100	120	S
Ramp-up rate to peak ^{*)} T_{smax} to T_{p}			2	3	K/s
Liquidus temperature	TL		217		°C
Time above liquidus temperature	t		80	100	S
Peak temperature	Τ _Ρ		245	260	°C
Time within 5 °C of the specified peak temperature T_p - 5 K	t _P	10	20	30	S
Ramp-down rate* T _P to 100 °C			3	6	K/s
Time 25 °C to T _P				480	S

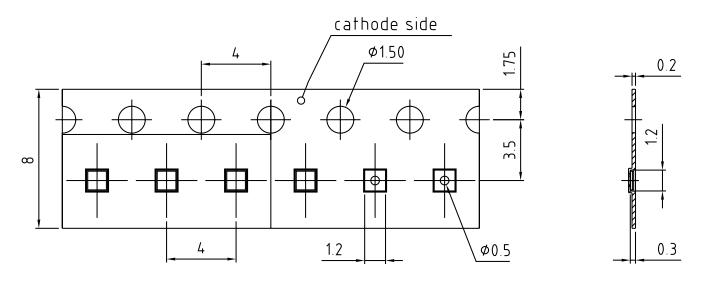
All temperatures refer to the center of the package, measured on the top of the component

* slope calculation DT/Dt: Dt max. 5 s; fulfillment for the whole T-range



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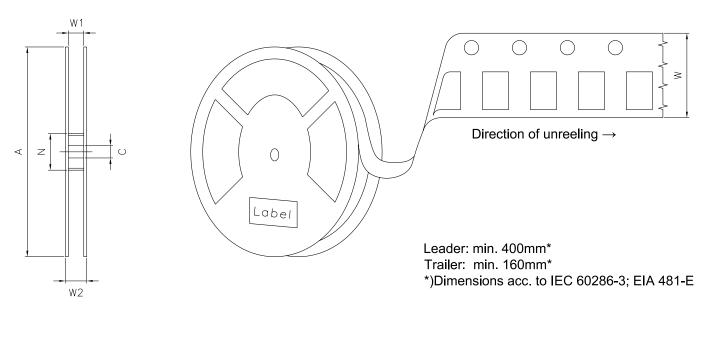
Taping 7)



C67062-A0296-B6 -04



Tape and Reel⁸⁾

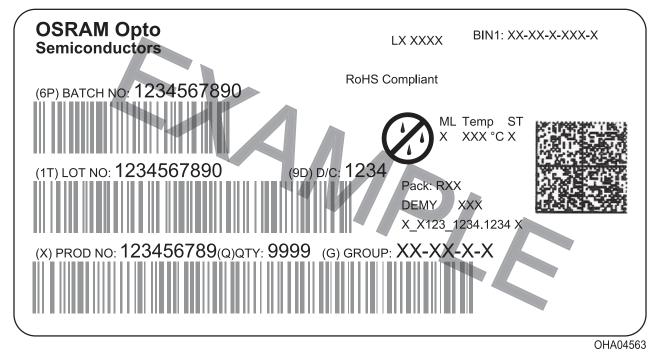


Reel Dimensions

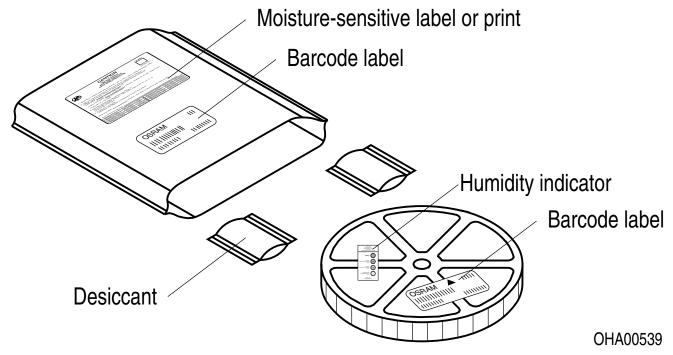
А	W	N _{min}	W ₁	$W_{2\text{max}}$	Pieces per PU
180 mm	12 + 0.3 / - 0.1 mm	60 mm	12.4 + 2 mm	18.4 mm	600



Barcode-Product-Label (BPL)



Dry Packing Process and Materials



Moisture-sensitive product is packed in a dry bag containing desiccant and a humidity card according JEDEC-STD-033.



Notes

The evaluation of eye safety occurs according to the standard IEC 62471:2006 (photo biological safety of lamps and lamp systems). Within the risk grouping system of this IEC standard, the device specified in this data sheet falls into the class **moderate risk (exposure time 0.25 s)**. Under real circumstances (for exposure time, conditions of the eye pupils, observation distance), it is assumed that no endangerment to the eye exists from these devices. As a matter of principle, however, it should be mentioned that intense light sources have a high secondary exposure potential due to their blinding effect. When looking at bright light sources (e.g. headlights), temporary reduction in visual acuity and afterimages can occur, leading to irritation, annoyance, visual impairment, and even accidents, depending on the situation.

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

This device is designed for specific/recommended applications only. Please consult OSRAM Opto Semiconductors Sales Staff in advance for detailed information on other non-recommended applications (e.g. automotive).

Change management for this component is aligned with the requirements of the lighting market.

For further application related information please visit www.osram-os.com/appnotes



Disclaimer

Attention please!

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version on the OSRAM OS website.

Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

Product and functional safety devices/applications or medical devices/applications

OSRAM OS components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

OSRAM OS products are not qualified at module and system level for such application.

In case buyer – or customer supplied by buyer – considers using OSRAM OS components in product safety devices/applications or medical devices/applications, buyer and/or customer has to inform the local sales partner of OSRAM OS immediately and OSRAM OS and buyer and /or customer will analyze and coordinate the customer-specific request between OSRAM OS and buyer and/or customer.



Glossary

- ¹⁾ **Brightness:** Brightness values are measured during a current pulse of typically 10 ms, with a tolerance of +/- 7%.
- ²⁾ **Reverse Operation:** Not designed for reverse operation. Continuous reverse operation can cause migration and damage of the device.
- ³⁾ **Wavelength:** The wavelength is measured at a current pulse of typically 10 ms, with a tolerance of ± 0.5 nm.
- ⁴⁾ **Forward Voltage:** The Forward voltage is measured during a current pulse duration of typically 1 ms with a tolerance of ± 0.05V.
- ⁵⁾ **Typical Values:** Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- ⁶⁾ **Characteristic curve:** In the range where the line of the graph is broken, you must expect higher differences between single devices within one packing unit.
- ⁷⁾ **Tolerance of Measure:** Unless otherwise noted in drawing, tolerances are specified with ±0.1 and dimensions are specified in mm.
- ⁸⁾ **Tape and Reel:** All dimensions and tolerances are specified acc. IEC 60286-3 and specified in mm.

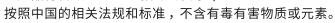


Revision HistoryVersionDateChange1.02020-03-23Initial Version1.02020-09-10Product Image1.12020-11-23Applications



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